





SN74LVC32A-Q1 SCAS706C - SEPTEMBER 2003 - REVISED MARCH 2024

SN74LVC32A-Q1 Automotive Quadruple 2-Input Positive-OR Gate

## 1 Features

Texas

- Qualified for automotive applications
- Operates from 2V to 3.6V
- Inputs accept voltages to 5.5V
- Max t<sub>pd</sub> of 3.8ns at 3.3V

INSTRUMENTS

- Typical V<sub>OLP</sub> (output ground bounce) < 0.8V at V<sub>CC</sub> • = 3.3V, T<sub>A</sub> = 25°C
- Typical  $V_{OHV}$  (output  $V_{OH}$  undershoot) > 2V at  $V_{CC}$ = 3.3V, T<sub>A</sub> = 25°C

## 2 Description

The SN74LVC32A-Q1 quadruple 2-input positive-OR gate is designed for 2.7V to 3.6V  $V_{CC}$  operation.

The device performs the Boolean function Y = A + B or  $Y = \overline{A \bullet B}$  in positive logic.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

Package Information
---------------------

	-							
PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE <sup>(3)</sup>					
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm					
SN74LVC32A-Q1	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm					
	PW (TSSOP, 14)	5mm × 6.4mm	5mm × 4.4mm					

(1) For more information, see Section 10.

(2)The package size (length × width) is a nominal value and includes pins, where applicable.

(3) The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Gate (Positive Logic)





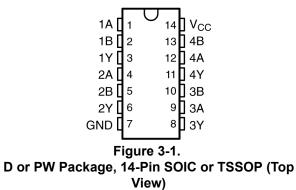
## **Table of Contents**

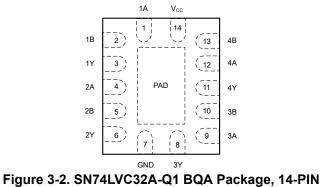
1 Features 2 Description	
3 Pin Configuration and Functions	
4 Specifications	.4
4.1 Absolute Maximum Ratings	
4.2 ESD Ratings	4
4.3 Recommended Operating Conditions	.4
4.4 Thermal Information	.4
4.5 Electrical Characteristics	.5
4.6 Switching Characteristics	.5
4.7 Operating Characteristics	5
5 Parameter Measurement Information	
6 Detailed Description	.7
6.1 Overview	.7
6.2 Functional Block Diagram	

	6.3 Device Functional Modes	7
7	Application and Implementation	8
	7.1 Power Supply Recommendations	8
	7.2 Layout	
	Device and Documentation Support	
	8.1 Documentation Support (Analog)	9
	8.2 Receiving Notification of Documentation Updates	
	8.3 Support Resources	
	8.4 Trademarks	
	8.5 Electrostatic Discharge Caution	
	8.6 Glossary	
	Revision History	
	) Mechanical, Packaging, and Orderable	
	Information	. 10



## **3 Pin Configuration and Functions**





WQFN (Top View)

#### Table 3-1. Pin Functions

PIN NAME NO.		TYPE <sup>(1)</sup>	DESCRIPTION		
			DESCRIPTION		
1A	1	I	Channel 1, Input A		
1B	2	I	Channel 1, Input B		
1Y	3	0	Channel 1, Output Y		
2A	4	I	Channel 2, Input A		
2B	5	I	Channel 2, Input B		
2Y	6	0	Channel 2, Output Y		
GND	7	_	Ground		
3Y	8	0	Channel 3, Output Y		
3A	9	I	Channel 3, Input A		
3B	10	I	Channel 3, Input B		
4Y	11	0	Channel 4, Output Y		
4A	12	I	Channel 4, Input A		
4B	13	I	Channel 4, Input B		
V <sub>cc</sub>	14	_	Positive Supply		
Thermal Info	rmation <sup>(2)</sup>	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.		

(1) Signal Types: I = Input, O = Output, I/O = Input or Output, P = Power Supply, G = Ground.

(2) For BQA package only.

# 4 Specifications

## 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range			-0.5	6.5	V
VI	Input voltage range <sup>(1)</sup>			-0.5	6.5	V
Vo	Output voltage range <sup>(1)</sup> <sup>(2)</sup>			-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	VI	< 0		-50	mA
I <sub>OK</sub>	Output clamp current	Vc	, < 0		-50	mA
I <sub>O</sub>	Continuous output current				±50	mA
	Continuous current through $V_{CC}  \text{or}$	GND			±100	mA
T <sub>stg</sub>	Storage temperature range			-65	150	°C

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

#### 4.2 ESD Ratings

		VALUE	UNIT
V	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
V (ESD)	Charged device model (CDM), per AEC Q100-011	±1000	V

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 4.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V	Supply voltage	Operating	2	3.6	V
V <sub>CC</sub>	Supply volage	Data retention only	1.5		v
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 2.7V to 3.6V	2		V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 2.7V to 3.6V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
1		V <sub>CC</sub> = 2.7V		-12	mA
юн		V <sub>CC</sub> = 3V		-24	
		V <sub>CC</sub> = 2.7V		12	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 3V		24	mA
Δt/Δv	Input transition rise or fall rate			7	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

#### **4.4 Thermal Information**

			SN74LVC32A-Q1		
		BQA (WQFN) D (SOIC) PW (TSSOP)			UNIT
		14 PINS	14 PINS	14 PINS	
R <sub>θJA</sub> Junction-to-ambient thermal resistance		102.3	86	113	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.



### **4.5 Electrical Characteristics**

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100μA	2.7V to 3.6V	V <sub>CC</sub> – 0.2		
V	I <sub>OH</sub> = -12mA	2.7V	2.2		V
V <sub>OH</sub>	$I_{OH} = -1210A$	3V	2.4		v
	$I_{OH} = -24 \text{mA}$	3V	2.2		
	I <sub>OL</sub> = 100μA	2.7V to 3.6V		0.2	
V <sub>OL</sub>	I <sub>OL</sub> = 12mA	2.7V		0.4	V
	I <sub>OL</sub> = 24mA	3V		0.55	
l <sub>l</sub>	V <sub>I</sub> = 5.5V or GND	3.6V		±5	μA
I <sub>CC</sub>	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6V		10	μA
ΔI <sub>CC</sub>	One input at $V_{CC}$ – 0.6V, Other inputs at $V_{CC}$ or GND	2.7V to 3.6V		500	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3V	5		pF

over recommended operating free-air temperature range (unless otherwise noted)

(1) All typical values are at  $V_{CC}$  = 3.3V,  $T_A$  = 25°C.

### 4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

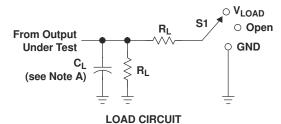
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>cc</sub> =	2.7V	V <sub>CC</sub> = ± 0.	3.3V 3V	UNIT
				MIN	MAX	MIN	MAX	
t <sub>pd</sub>		A or B	Y		4.4	1	3.8	ns

## 4.7 Operating Characteristics

T<sub>A</sub> = 25°C

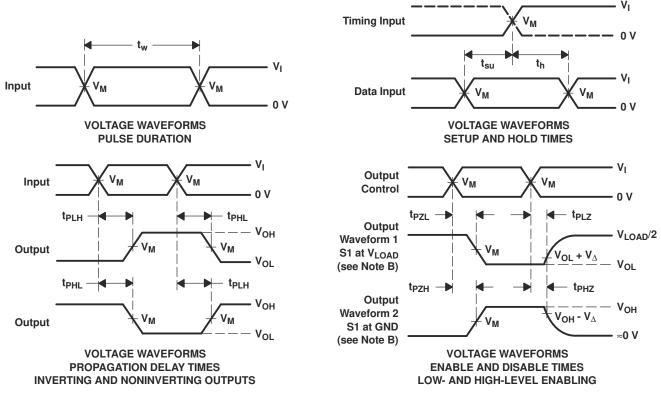
	PARAMETER	TEST CONDITIONS	$V_{CC}$ = 2.5V	V <sub>CC</sub> = 3.3V	UNIT
		TEST CONDITIONS	TYP	TYP	
C	Power dissipation capacitance per gate	f = 10MHz	10.6	12.5	pF

### **5** Parameter Measurement Information



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INF	PUTS	N	V	•			
V <sub>CC</sub>	VI t <sub>r</sub> /t <sub>f</sub>		VM	V <sub>LOAD</sub>	CL	RL	$V_{\Delta}$	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V	
$3.3 \text{ V} \pm 0.3 \text{ V}$	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V	



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ .

  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

#### Figure 5-1. Load Circuit and Voltage Waveforms



## 6 Detailed Description

### 6.1 Overview

The device performs the Boolean function Y = A + B or  $Y = \overline{\overline{A} \bullet \overline{B}}$  in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

### 6.2 Functional Block Diagram



Figure 6-1. Logic Diagram, Each Gate (Positive Logic)

#### 6.3 Device Functional Modes

Function Table (Each Gate)									
INPUTS OUTPUT									
Α	В	Y							
Н	Х	Н							
x	Н	Н							
L	L	L							



### 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in given example layout image.

#### 7.2 Layout

#### 7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 7.2.2 Layout Example

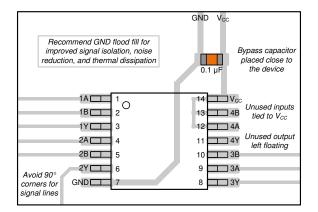


Figure 7-1. Example Layout for the SN74LVC32A-Q1



### 8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 8.1 Documentation Support (Analog)

#### 8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY					
SN74LVC32A-Q1	Click here	Click here	Click here	Click here	Click here					

#### Table 8-1. Related Links

#### 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

#### **9 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision B (February 2008) to Revision C (March 2024)

- Page
- Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section
- Added BQA package to Package Information table, Pin Configuration and Functions section, and Thermal
  Information table



## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74LVC32AQDRQ1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32AQ	Samples
SN74LVC32AQPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32AQ	Samples
SN74LVC32AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32AQ	Samples
SN74LVC32AWBQARQ1	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32Q	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



www.ti.com

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74LVC32A-Q1 :

- Catalog : SN74LVC32A
- Enhanced Product : SN74LVC32A-EP
- Military : SN54LVC32A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications



www.ti.com

## TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC32AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1



www.ti.com

# PACKAGE MATERIALS INFORMATION

20-Mar-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC32AQPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC32AQPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC32AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

## **BQA 14**

2.5 x 3, 0.5 mm pitch

# **GENERIC PACKAGE VIEW**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





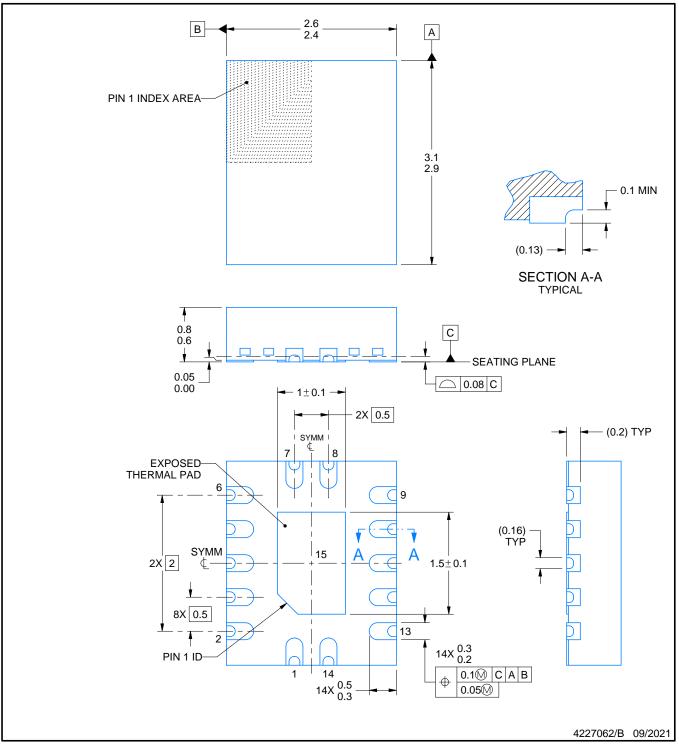
# **BQA0014B**



## **PACKAGE OUTLINE**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

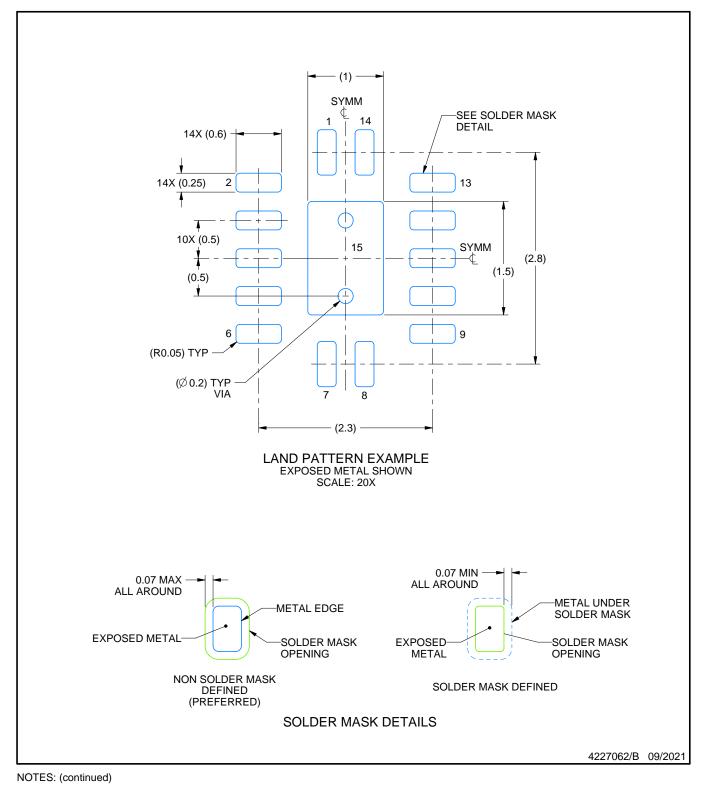


## **BQA0014B**

# **EXAMPLE BOARD LAYOUT**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

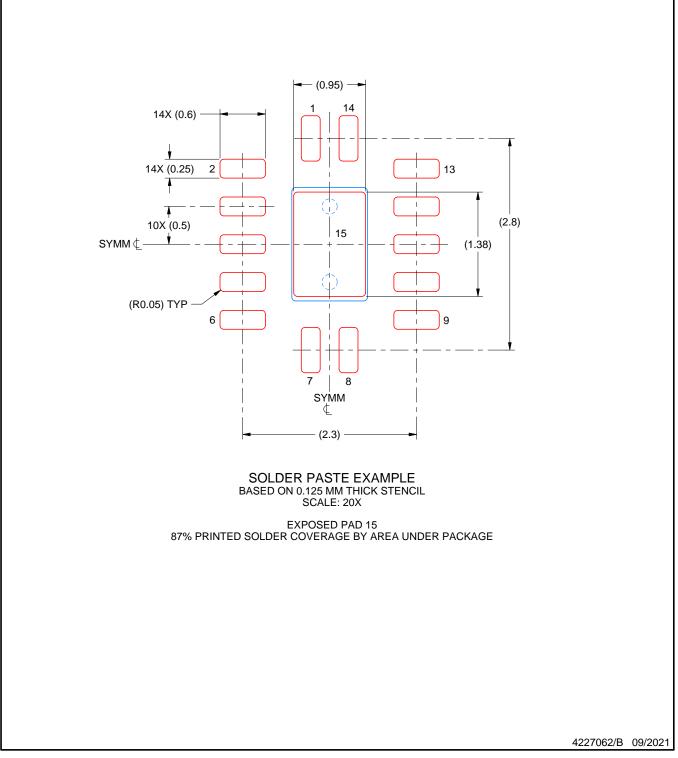


## **BQA0014B**

# **EXAMPLE STENCIL DESIGN**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated